

SGA-1263(Z) DCto4000MHz SILICON GERMANIUM HBT **CASCADABLE GAIN BLOCK**

Package: SOT-363



Si BJT

GaN HEMT

InP HBT **RF MEMS**

LDMOS

Product Description

RFMD's SGA-1263(Z) is a Silicon Germanium HBT Heterostructure Bipolar Transistor (SiGe HBT) amplifier that offers excellent isolation and flat gain response for application to 4GHz. This RFIC is a 2-stage design that provides high isolation of up to 40dB at 2GHz and is fabricated using the latest SiGe HBT 50GHz FT process, featuring one-micron emitters with V_{CEO} >7 V. These unconditionally stable amplifiers have less than 1dB gain drift over 125°C operating range (-40°C to +85°C) and are ideal for use

as buffer amplifiers in oscillator applications covering



200

006

-80

8

Features

- DCto400MHz Operation
- Single Supply Voltage
- Excellent Isolation, >50dB at 900 MHz
- 50W In/Out, Broadband Match for Operation from DC-4GHz
- Unconditionally Stable

Applications

- Buffer Amplifier for Oscillator Applications
- Broadband Gain Blocks
- IF Amp

| Parameter | Specification | | | Unit | Condition |
|------------------------------------|---------------|------|------|------|-----------|
| | Min. | Тур. | Max. | Unit | Condition |
| Small Signal Gain | 15 | 17 | 19 | dB | 850MHz |
| | 12 | 15 | 17 | dB | 1950MHz |
| Output Power at 1dB Compression | -13.0 | -9.5 | | dBm | 1950MHz |
| Output Third Order Intercept Point | -1.5 | 1.0 | | dBm | 1950MHz |
| Determined by Return Loss (<-10dB) | | | | MHz | |
| Input Return Loss | 9.5 | 11.2 | | dB | 1950MHz |
| Output Return Loss | 7 | 8 | | dB | 1950MHz |
| Noise Figure | | 2.5 | 4.0 | dB | 1950MHz |
| Device Voltage | 2.5 | 2.8 | 3.1 | V | |
| Thermal Resistance | | 255 | | °C/W | |
| | | | | | |

2400

006

Frequency MHz

3500

6000

Test Conditions: $V_S = 5V$, $I_D = 8$ mA Typ., OIP3 Tone Spacing = 1MHz, P_{OUT} per tone = -20 dBm, $R_{BIAS} = 270\Omega$, $T_L = 25$ °C, $Z_S = Z_L = 50\Omega$

SGA-1263(Z)



Absolute Maximum Ratings

| - | | |
|----------------------------------|------------|------|
| Parameter | Rating | Unit |
| Max Device Current (ID) | 20 | mA |
| Max Device Voltage (VD) | 5 | V |
| Max RF Input Power | -12 | dBm |
| Max Junction Temperature (TJ) | +150 | °C |
| Operating Temperature Range (TL) | -40 to +85 | °C |
| Max Storage Temperature | +150 | °C |

Operation of this device beyond any one of these limits may cause permanent dam-age. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one. Bias Conditions should also satisfy the following expression:

 $I_D V_D < (T_J - T_L) / R_{TH}$, j-l

Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical perfor-mance or functional operation of the device under Absolute Maximum Rating condi-tions is not implied.

RoHS status based on EU Directive 2002/95/EC (at time of this document revision).

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| Parameter | Specification | | | Unit | Condition | |
|-------------------|---------------|------|------|------|-----------|--|
| | Min. | Тур. | Max. | Unit | Condition | |
| Bandwidth | | | | | T=25°C | |
| Frequency Range | DC | | 4000 | MHz | | |
| Device Bias | | | | | T=25°C | |
| Operating Voltage | | 2.8 | | V | | |
| Operating Current | | 8 | | mA | | |
| 500MHz | | | | | T=25°C | |
| Gain | | 16.0 | | dB | | |
| Noise Figure | | 2.7 | | dB | | |
| Output IP3 | | 4.0 | | dBm | | |
| Output P1dB | | -6.9 | | dBm | | |
| Input Return Loss | | 8.5 | | dB | | |
| Isolation | | 61.6 | | dB | | |
| 850MHz | | | | | T=25°C | |
| Gain | | 15.7 | | dB | | |
| Noise Figure | | 2.7 | | dB | | |
| Output IP3 | | 2.6 | | dBm | | |
| Output P1dB | | -7.8 | | dBm | | |
| Input Return Loss | | 8.9 | | dB | | |
| Isolation | | 48.4 | | dB | | |
| 1950 MHz | | | | | T=25°C | |
| Gain | | 14.7 | | dB | | |
| Noise Figure | | 3.0 | | dB | | |
| Output IP3 | | 2.8 | | dBm | | |
| Output P1dB | | -7.4 | | dBm | | |
| Input Return Loss | | 8.8 | | dB | | |
| Isolation | | 35.6 | | dB | | |
| 2400 MHz | | | | | T=25°C | |
| Gain | | 14.2 | | dB | | |
| Noise Figure | | 2.8 | | dB | | |
| Output IP3 | | 0.2 | | dBm | | |
| Output P1dB | | -7.0 | | dBm | | |
| Input Return Loss | | 8.4 | | dB | | |
| Isolation | | 33.6 | | dB | | |





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| Pin | Function | Description |
|-----|----------|--|
| 1 | GND | Connection to ground. Use via holes for best performance to reduce lead inductance as close to ground leads as possible. |
| 2 | GND | Same as Pin 1. |
| 3 | RF IN | RF input pin. This pin requires the ise of an external DC blocking capacitor chosen for the frequency of operation. |
| 4 | VCC | Supply Connection. This pin should be bypassed with suitable capacitor(s). |
| 5 | GND | Same as Pin 1. |
| 6 | RF OUT | RF output and bias pin. DC voltage is present on this pin, therefore a DC blocking capacitor is necessary for proper oper ation. |

Application Schematic for +5V Operation at 900 MHz



Application Schematic for +5V Operation at 1900 MHz



| Recommended Bias Resistor | | | | or Valu | es |
|---------------------------|------|-----|------|---------|------|
| Supply Voltage(Vs) | 3.6V | 5V | 7.5V | 9V | 12V |
| Rbias (Ohms) | 100 | 275 | 588 | 775 | 1150 |

SGA-1263(Z)





DS090924







Package Dimensions





Part Identification Marking



RoHS Compliant part will be indicated with a "12Z" part marking.

Alternate Marking with Trace Code Only



| Part Number | Description | Reel Size | Devices/Reel |
|-------------|---------------------------|-----------|--------------|
| SGA-1263 | Tin-Lead | 7" | 3000 |
| SGA-1263Z | Lead Free, RoHS Compliant | 7" | 3000 |